

Notice of Allowability

Application No.

10/720,094

Examiner

Thomas L. Dickey

Applicant(s)

BITO, YASUNORI

Art Unit

2826

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address--

All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. **THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS.** This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.

1. This communication is responsive to drawings and amendment filed 2/2/06.2. The allowed claim(s) is/are 1-8, 10-13 and 15-18.3. Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).a) All b) Some* c) None of the:1. Certified copies of the priority documents have been received.2. Certified copies of the priority documents have been received in Application No. _____.3. Copies of the certified copies of the priority documents have been received in this national stage application from the International Bureau (PCT Rule 17.2(a)).

* Certified copies not received: _____.

Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application.
THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.

4. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.5. CORRECTED DRAWINGS (as "replacement sheets") must be submitted.(a) including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached
1) hereto or 2) to Paper No./Mail Date _____.(b) including changes required by the attached Examiner's Amendment / Comment or in the Office action of
Paper No./Mail Date _____.

Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).

6. DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.**Attachment(s)**

1. Notice of References Cited (PTO-892)
2. Notice of Draftsperson's Patent Drawing Review (PTO-948)
3. Information Disclosure Statements (PTO-1449 or PTO/SB/08),
Paper No./Mail Date 10/17/2005
4. Examiner's Comment Regarding Requirement for Deposit
of Biological Material
5. Notice of Informal Patent Application (PTO-152)
6. Interview Summary (PTO-413),
Paper No./Mail Date _____.
7. Examiner's Amendment/Comment
8. Examiner's Statement of Reasons for Allowance
9. Other _____.

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EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

The application has been amended as follows:

IN THE CLAIMS:

Cancel claims 19-35.

DRAWINGS

2. The proposed drawing correction and/or the proposed substitute sheets of drawings, filed on 02/02/2006 have been approved.

REASONS FOR ALLOWANCE

3. The following is an examiner's statement of reasons for allowance:

Claims 1-8, 10-13 and 15-18 are allowed over the references of record because none of these references disclosed or can be combined to yield the claimed invention such as a heterojunction field effect type semiconductor device, comprising a GaAs substrate; a channel layer formed over said GaAs substrate; a first semiconductor layer including no aluminum formed over said channel layer; a cap layer of a first conductivity

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type formed on said first semiconductor layer, said cap layer creating a first recess on said first semiconductor layer; first and second ohmic electrodes formed on said cap layer, respectively; a second semiconductor layer of second conductivity type formed on said first semiconductor layer within said first recess, said second semiconductor layer being isolated from said cap layer; a gate electrode formed on said second semiconductor layer; and a third semiconductor layer interposed between said first semiconductor layer and said cap layer and having a second recess, said second semiconductor layer passing through the second recess of said third semiconductor layer to reach said first semiconductor layer, said third semiconductor layer comprising a GaAs layer formed on an AlGaAs layer, as recited in claim 1.

As was noted in the Paper mailed 6/16/05, Kato et al. discloses a heterojunction field effect type semiconductor device with all the limitations of claim 1 except Kato et al.'s two part GaAs/AlGaAs third semiconductor layer has a first AlGaAs part 511 formed on a second GaAs part 510. Claim 1 requires the second GaAs part of the third layer to be formed on the first AlGaAs part.

4. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

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Conclusion

1. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thomas L Dickey whose telephone number is 571-272-1913. The examiner can normally be reached on Monday-Thursday 8-6.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan J Flynn can be reached on 571-272-1915. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).



Thomas L. Dickey
Patent Examiner
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02/06